



Vishay General Semiconductor

High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V_{RRM}	90 V, 100 V				
I _{FSM}	50 A				
V_{F}	0.62 V				

1.0 µA

175 °C

 I_R

T_{.I} max.

FEATURES

- High barrier technology for improved high T_J
- Guardring for overvoltage protection
- Low power losses and high efficiency
- · Low forward voltage drop
- Very low leakage current
- · High forward surge capability
- · High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in middle voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

MECHANICAL DATA

Case: DO-204AL (DO-41)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SB1H90	SB1H100	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V	
Maximum RMS voltage	V _{RMS}	63 70		V	
Maximum DC blocking voltage	V_{DC}	90	100	V	
Maximum average forward rectified current	I _{F(AV)}	1.0		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50		А	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Peak repetitive reverse surge current at t_p = 2.0 μ s, 1 kHz	I _{RRM}	1.0		А	
Maximum operating junction temperature	TJ	175		°C	
Storage temperature range	T _{STG}	- 55 to + 175		°C	

SB1H90, SB1H100

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	SB1H90	SB1H100	UNIT
Maximum instantaneous forward voltage	I _F = 1.0 A	T _J = 25 °C	V _F ⁽¹⁾	0.77		V
		T _J = 125 °C		0.62		
	I _F = 2.0 A	T _J = 25 °C		0.	86	V
		T _J = 125 °C		0.70		70
Maximum reverse current at rated V _R	T _J = 25 °C T _J = 125 °C	I _R ⁽²⁾	1	.0	μΑ	
		T _J = 125 °C	IR ^(≥)	0	.5	mA

Notes

 $^{(1)}$ Pulse test: 300 ms pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SB1H90	SB1H100	UNIT	
Maximum thermal resistance	R _{0JA} (1)	57		°C/W	
Waximum thermal resistance	R _{0JL} (1)	15			

Note

 $^{(1)}$ P.C.B. mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE BASE QUANTIT		DELIVERY MODE		
SB1H100-E3/54	0.34	54	5500	13" diameter paper tape and reel		
SB1H100-E3/73	0.34	73	3000	Ammo pack packaging		
SB1H100HE3/54 ⁽¹⁾	0.34	54	5500	13" diameter paper tape and reel		
SB1H100HE3/73 ⁽¹⁾	0.34	73	3000	Ammo pack packaging		

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

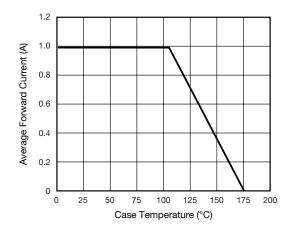


Fig. 1 - Forward Current Derating Curve

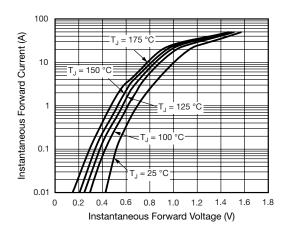


Fig. 2 - Typical Instantaneous Forward Characteristics

⁽¹⁾ AEC-Q101 qualified





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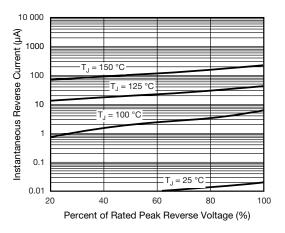


Fig. 3 - Typical Reverse Characteristics

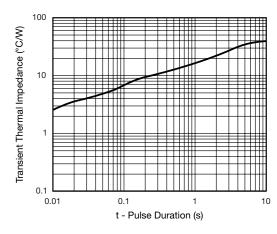


Fig. 5 - Typical Transient Thermal Impedance

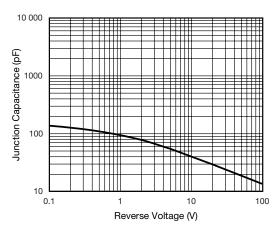
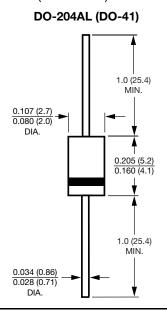


Fig. 4 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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